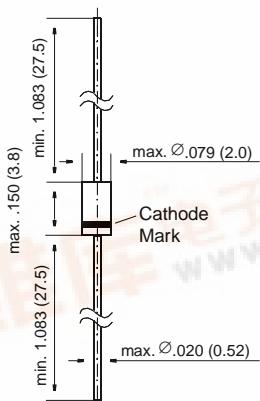


# BAV19 THRU BAV21

## Small Signal Diodes

DO-35



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Silicon Epitaxial Planar Diodes
- ◆ For general purpose
- ◆ These diodes are also available in other case styles including: the SOD-123 case with the type designation BAV19W - BAV21W, the MiniMELF case with the type designation BAV101 - BAV103, and the SOT-23 case with the type designation BAS19 - BAS21.



### MECHANICAL DATA

**Case:** DO-35 Glass Case

**Weight:** approx. 0.13 g

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Reverse Voltage <b>BAV19</b> <b>BAV20</b> <b>BAV21</b>	V <sub>R</sub>	120	V
	V <sub>R</sub>	200	V
	V <sub>R</sub>	250	V
Forward DC Current at T <sub>amb</sub> = 25 °C	I <sub>F</sub>	250 <sup>1)</sup>	mA
Rectified Current (Average) Half Wave Rectification with Resist. Load at T <sub>amb</sub> = 25 °C and f ≥ 50 Hz	I <sub>0</sub>	200 <sup>1)</sup>	mA
Repetitive Peak Forward Current at f ≥ 50 Hz, Θ = 180 °, T <sub>amb</sub> = 25 °C	I <sub>FRM</sub>	625 <sup>1)</sup>	mA
Surge Forward Current at t < 1 s, T <sub>j</sub> = 25 °C	I <sub>FSM</sub>	1	A
Power Dissipation at T <sub>amb</sub> = 25 °C	P <sub>tot</sub>	500 <sup>1)</sup>	mW
Junction Temperature	T <sub>j</sub>	175 <sup>1)</sup>	°C
Storage Temperature Range	T <sub>s</sub>	-65 to +175 <sup>1)</sup>	°C

<sup>1)</sup> Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case

# BAV19 THRU BAV21

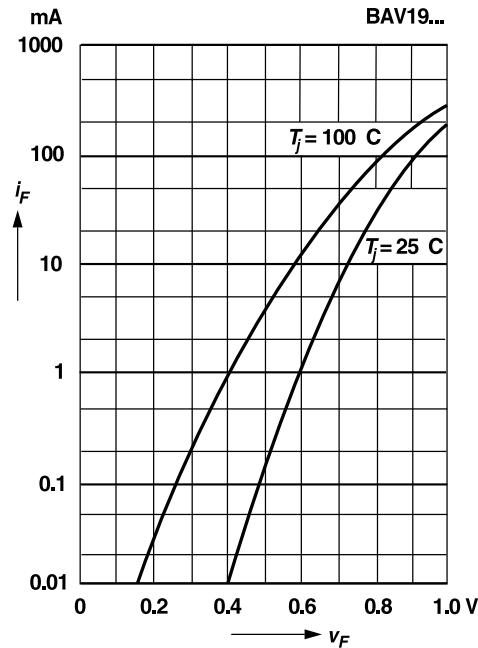
## ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Typ.	Max.	Unit
Forward voltage at $I_F = 100 \text{ mA}$	$V_F$	—	—	1	V
Leakage Current at $V_R = 100 \text{ V}$ $\text{BAV19}$	$I_R$	—	—	100	nA
at $V_R = 100 \text{ V}, T_j = 100 \text{ }^\circ\text{C}$ $\text{BAV19}$	$I_R$	—	—	15	$\mu\text{A}$
at $V_R = 150 \text{ V}$ $\text{BAV20}$	$I_R$	—	—	100	nA
at $V_R = 150 \text{ V}, T_j = 100 \text{ }^\circ\text{C}$ $\text{BAV20}$	$I_R$	—	—	15	$\mu\text{A}$
at $V_R = 200 \text{ V}$ $\text{BAV21}$	$I_R$	—	—	100	nA
at $V_R = 200 \text{ V}, T_j = 100 \text{ }^\circ\text{C}$ $\text{BAV21}$	$I_R$	—	—	15	$\mu\text{A}$
Dynamic Forward Resistance at $I_F = 10 \text{ mA}$	$r_f$	—	5	—	$\Omega$
Capacitance at $V_R = 0, f = 1 \text{ MHz}$	$C_{tot}$	—	1.5	—	pF
Reverse Recovery Time from $I_F = 30 \text{ mA}$ through $I_R = 30 \text{ mA}$ to $I_R = 3 \text{ mA}; R_L = 100 \Omega$	$t_{rr}$	—	—	50	ns
Thermal Resistance Junction to Ambient Air	$R_{thJA}$	—	—	375 <sup>1) 2)</sup>	K/W
<sup>1)</sup> Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case					

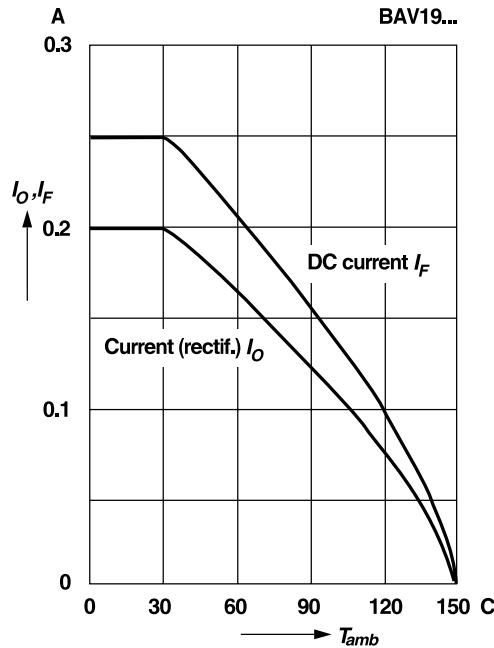
## RATINGS AND CHARACTERISTIC CURVES BAV19 THRU BAV21

**Forward characteristics**



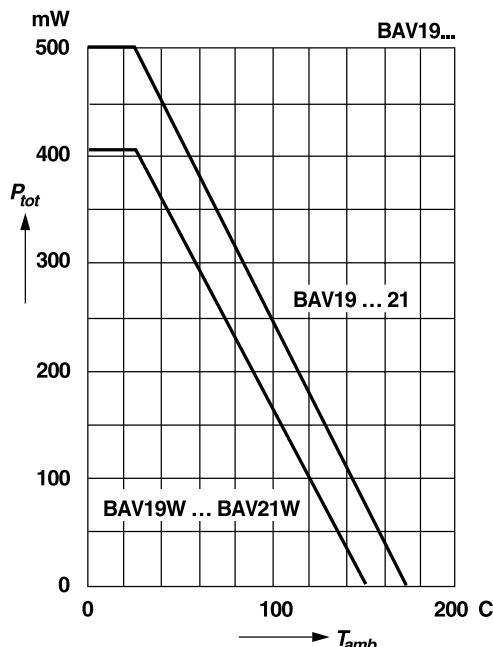
**Admissible forward current versus ambient temperature**

For conditions, see footnote in table  
"Absolute Maximum Ratings"

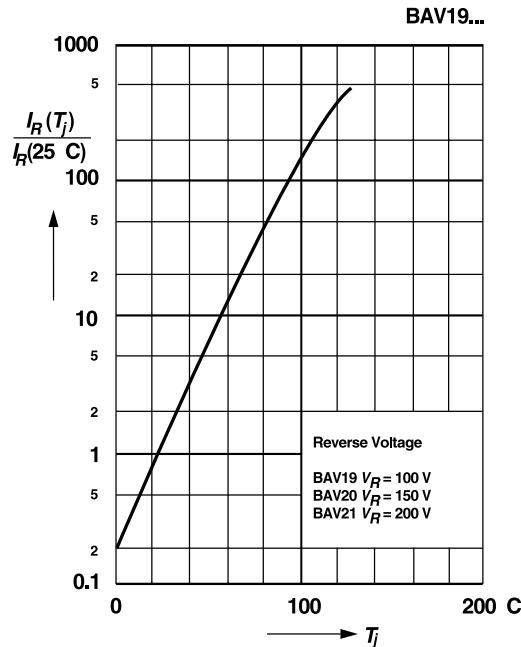


**Admissible power dissipation versus ambient temperature**

For conditions, see footnote in table  
"Absolute Maximum Ratings"



**Leakage current versus junction temperature**

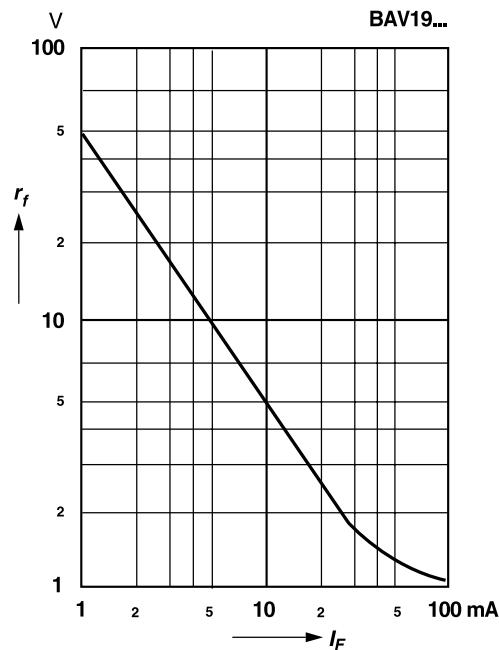


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## RATINGS AND CHARACTERISTIC CURVES BAV19 THRU BAV21

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Dynamic forward resistance  
versus forward current



Capacitance  
versus reverse voltage

